

Supporting Information

Multiscale Synergetic Bandgap/Structure Engineering to Construct Full-Spectrum Responsive Heterostructured MoS₂/SnS₂ Photocatalysts

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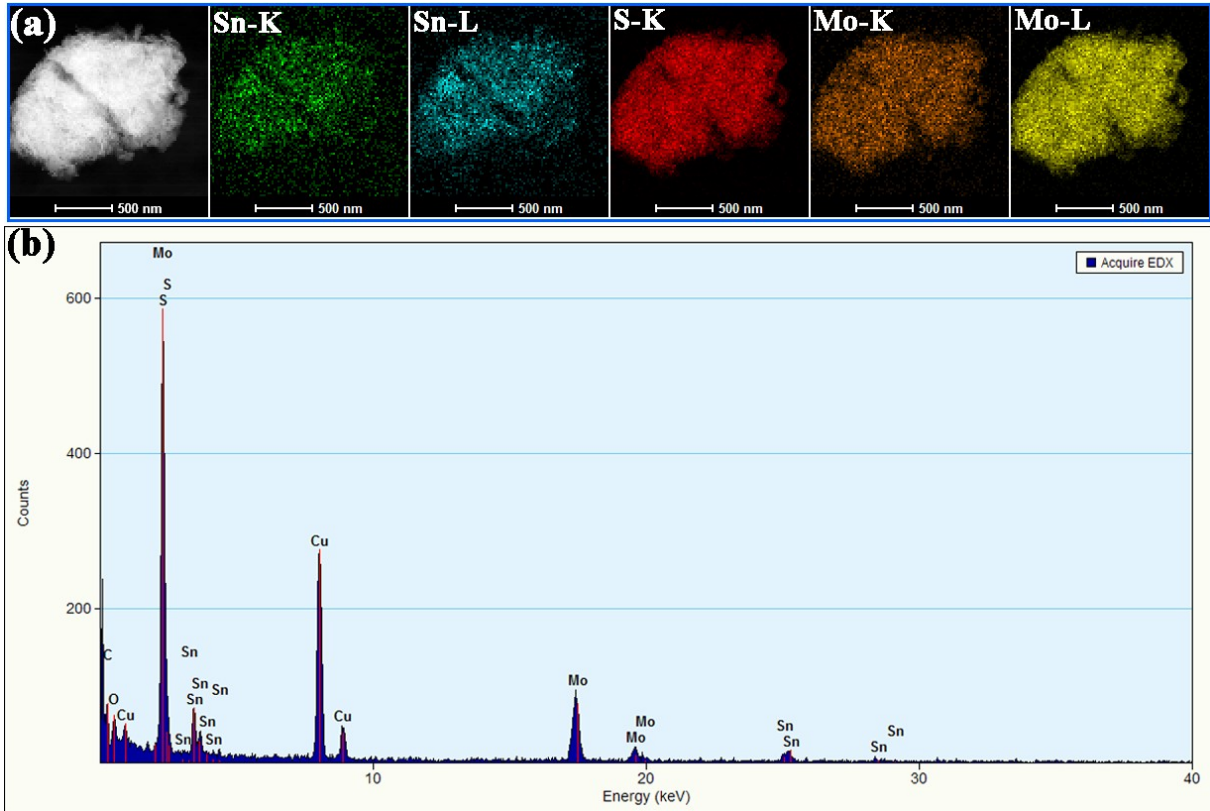
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27

28

Supporting Information

29 ■ RESULTS AND DISCUSSION



30

31

Fig- S1. (a) EDX elemental mapping and (b) EDX spectrum of MoS₂/SnS₂ heterostructure.

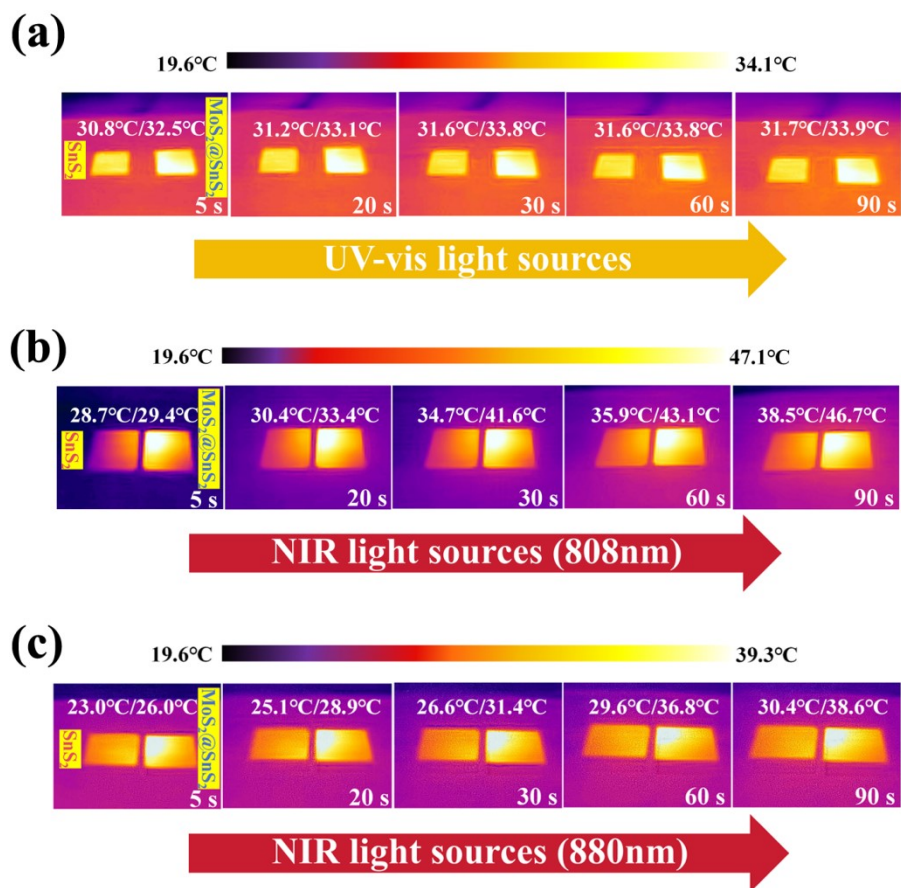


Figure S2. The time-dependent temperature and thermal image for SnS₂ and MoS₂/SnS₂ under UV-vis light and NIR light (808 and 880 nm) irradiation.

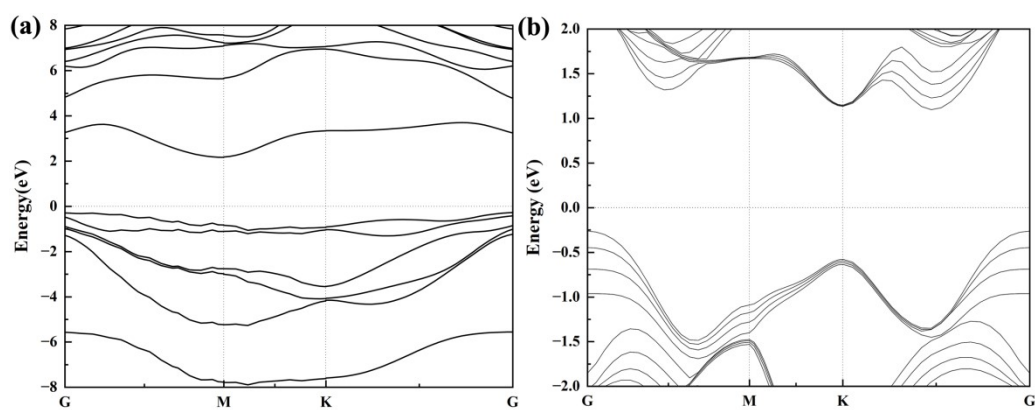
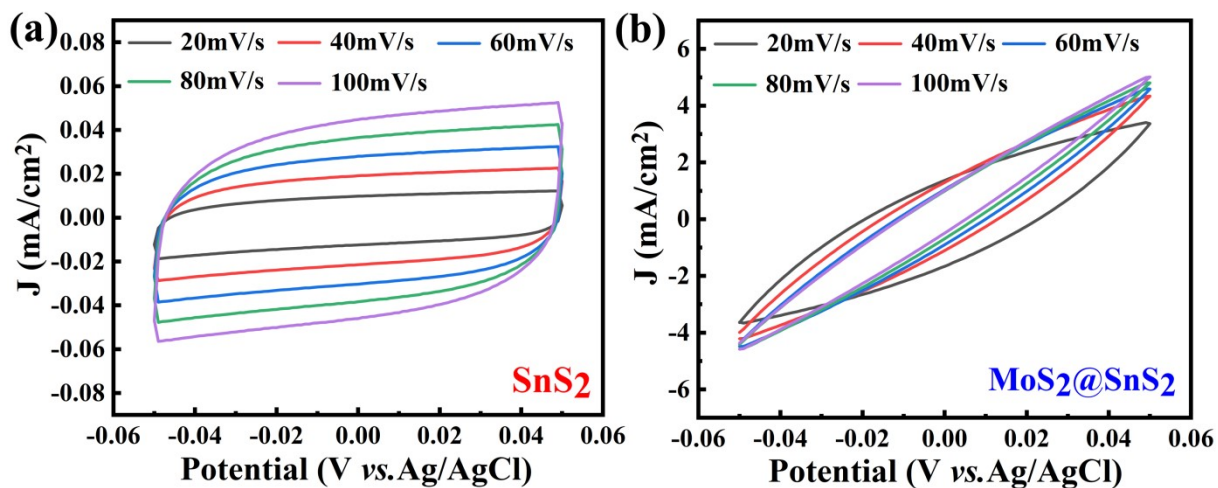


Figure S3. (a) Band structure of the original SnS₂ monolayer. (b) Band structure of the original MoS₂ multilayer.



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Fig- S4. Cyclic voltammetry (CV) of at various scan rates for (a) SnS₂ and (b) MoS₂/SnS₂.

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Table S1. The simulated parameter values obtained by fitting the Nyquist plots.

Samples	SnS ₂	MoS ₂ @SnS ₂
R _s (ohm)	7.94	8.94
R _{ct} (ohm)	566.8	3.56
CPE1(mF)	912.71	685.86

47